SA7110B: 64 Bit Read-only Manchester Coded Transponder



FEATURES

- EEPROM flexibility of data configuration
- 64 bits of OTP data factory programmed and locked
- Customer specific configuration of stored data
- Data output in Manchester mode
- Carrier frequency 100 to 300 kHz
- On-chip resonance capacitor

- No external charge storage capacitor required
- On-chip full wave rectifier
- On-chip data modulator
- On-chip high voltage protection / regulation
- On-chip RF frequency clock extractor / prescaler
- Low power dissipation

DESCRIPTION

This device is manufactured in the SAMES 1.2µm N-well EEPROM process. It has 64 bits, factory preprogrammed and locked in EEPROM memory. Read data is Manchester coded.

The device has an on-chip rectification circuit that converts the incoming rf signal to DC power feeding V_{DD}.

There is also an on-chip data modulator, which works in conjunction with the rectifier. The time base is extracted by an on-chip RF clock extractor. High voltage protection Sheet4U.com across the coil inputs is provided internally. The energy is stored on capacitance on chip due to low internal power consumption. The device has an on-chip resonance capacitor connected between the COIL1 and COIL2 pads. These features result in a single external component count, comprised of, only the coil.

Data is read at the RF interface by means of the on-chip modulator. The stored bits are clocked out sequentially during the read operation. An internal power-on reset is provided which allows the device to start reading out data at low voltages for improved tag range.

APPLICATIONS

- Access Control
- Industrial automation
- Asset tracking

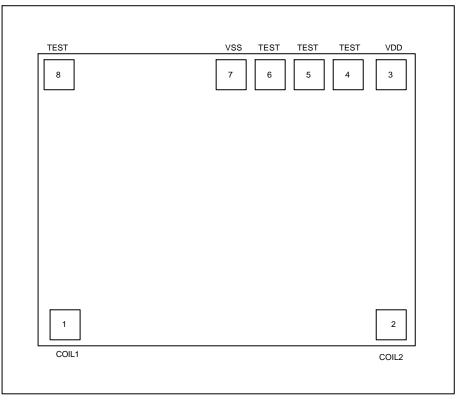
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PAD CONNECTIONS



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PAD DESCRIPTION

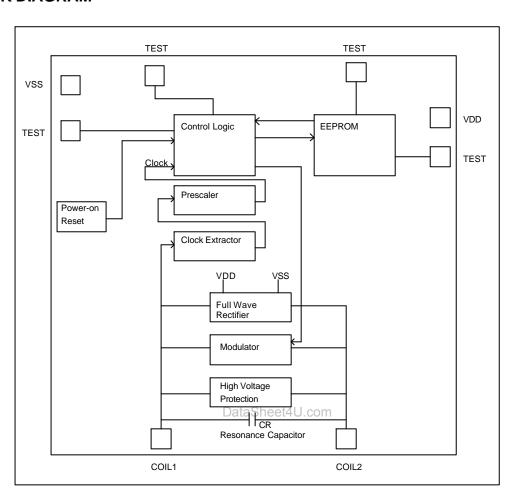
PAD No.	NAME	DESCRIPTION				
1	COIL1	External coil connection				
2	COIL2	External coil connection				
3	V _{DD}	Supply voltage				
4	TEST	Test Pad				
5	TEST	Test Pad				
6	TEST	Test Pad				
7	V _{SS}	Ground				
8	TEST	Test Pad				

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BLOCK DIAGRAM



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ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	MIN	MAX	UNIT	NOTE
Supply Voltage	V_{DD}	-0.3	9.4	V	1,2,3,4,5
ESD protection C= 100pF R = 1.5Kohm, Human body model. MIL-STD-883C method 3015	Vpesd	-	TBD	٧	3,8
Peak voltage across COIL1 or COIL2 to V _{SS}	V _{COIL1,2} - V _{SS}	-10	+10	٧	3,6
Peak current through COIL 1,2	I _{COIL1,2}	-30	+30	mA	3,7
Storage temperature	Tst	-55	+125	°C	3

Note 1: Duration not to exceed 10 seconds, and no logic switching.

Note 2: Referenced to Vss

Note 3: Stresses above those listed under "absolute maximum ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operating conditions section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect the device reliability.

Note 4: VDD level when absolute maximum current goes through coil inputs.

Note 5: VDD level when absolute maximum voltage is across coil inputs.

Note 6: Maximum peak voltage at COIL1 or COIL2 of incoming RF signal with Vss as reference. Clamping by front-end

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Note 7: Maximum allowed peak current of incoming RF signal.

Note 8: TBD - To be determined.

HANDLING PROCEDURES

Although the device has built-in ESD protection, adherence to anti-static procedures for CMOS devices is required.

ELECTRICAL CHARACTERISTICS

DC Operating Conditions

Parameter	Symbol	Min	Тур	Max	Unit	Condition
Dynamic current	I _{DD}		3	6	μΑ	$V_{DD} = 3V$
Static current	I _{DDS}			1	μA	V _{DD} = 3V, clock stopped, COIL1 & COIL2 shorted to V _{SS}
Voltage when power-on reset comes out of reset	V _{POR}	1.2	1.6	2	٧	During power-up V _{DD} – V _{SS} rising
Histereses on power-on rest	V _{PORH}	200	ı	600	mV	Between coming out of reset and going back into reset
Data retention	T _{DR}	10		-	years	programmed
Supply voltage	V _{DD}	2	1	5.5 ₁₎	V	At specified current at COIL1 or COIL2,
Operating temperature	Тор	-40		+70	ပ	

Note: 1) maximum voltage is defined when forcing 10 mA on the coil inputs.

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AC Operating Conditions Clocking

Parameter	Symbol	Min	Тур	Max	Unit	Condition
RF carrier frequency at COIL1,2	f _{RF}	50	125	300	kHz	Sustained RF from base station
Number of rf carrier cycles per bit	N _B	32	64	-		

Coil Inputs

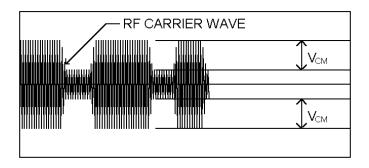
Parameter	Symbol	Min	Тур	Max	Unit	Condition
Negative excursion of COIL1 or COIL2	V _{CN}	-0.6	-0.65	-0.7	V	Peak level referenced to VSS
Modulated voltage drop	V _{СМ}	TBD	3.3	TBD	V	Unmodulated COIL1 or COIL2 voltage referenced to $V_{SS} = 5.5V$
Modulated voltage drop	V _{СМ}	TBD	3.0	TBD	V	Unmodulated COIL1 or COIL2 voltage referenced to V _{SS} = 5.0V
Modulated voltage drop	V _{СМ}	TBD	0.875	TBD	V	Unmodulated COIL1 or COIL2 voltage referenced to V _{SS} = 2.5
Resonance Capacitor	C _R	1)	170	1)	pF	Measured between COIL1 and COIL2

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Note: 1) for a single batch the tolerance is $\pm 3\%$. From batch to batch the tolerance is $\pm 30\%$.

TBD - To be determined.

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FUNCTIONAL DESCRIPTION

The circuit is built up out of several functional blocks, control logic, coil interface, the power-on reset, and the memory module (EEPROM). The chip activates automatically during power-up as a result of the built in power-on reset.

Coil Interface

Power is derived from a full wave rectifier bridge. Data modulation takes place by loading the coil inputs to the bridge with a modulating circuit. The coil interface includes on-chip high voltage protection. The system clock for the chip is derived by means of a clock extractor coupled to the rectifier circuit. The Clock extractor / prescaler is the time base generator for data reading. Data is read from the EEPROM to the coil interface where the rf signal is modulated by the data in the Manchester coded mode.

Memory Array

Data storage:

The data EEPROM is arranged in an 8X8 bit array cycle composed of 8 columns of 8 bit bytes. The 64 bits of data stored in the array can be configured in any way as agreed with the client, and is factory programmed and heet4U.com

locked in that way. This gives OTP (One Time Programmable) security.

Memory map

The flexibility of programming allows custom memory mapping.

Control logic

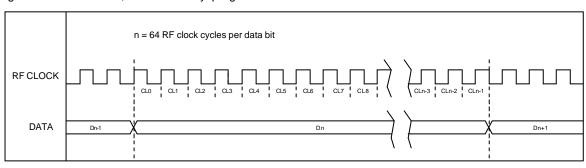
The control logic gets its clock from the clock extractor / prescaler and facilitates the reading of the data stored in the data EEPROM.

TIMING SPECIFICATIONS

The COIL1 and COIL2 pads modulate the incoming rf signal with Manchester encoded data. The data will repeatedly be read out serially until the power is reduced sufficiently to activate the power on reset again. There are 64 rf carrier cycles for each data bit. This is the nominal setting. An optional hardware setting of 32 rf cycles per bit can be selected during wafer manufacture.

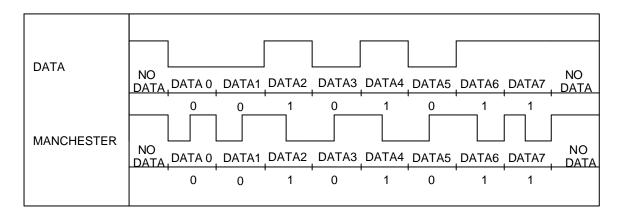
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DATA OUTPUT

Data output takes place according to Manchester encoding.



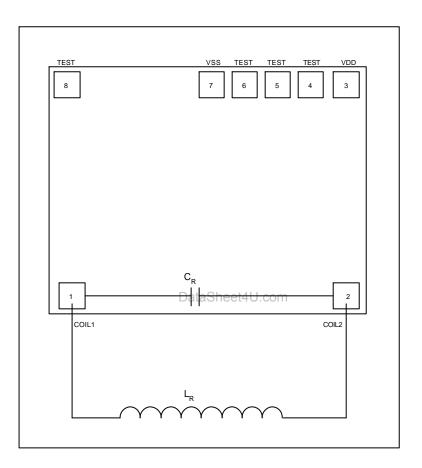
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TYPICAL APPLICATION

The chip powers up via the COIL1 and COIL2 pads, deriving its energy from the rf carrier wave through the resonating tank circuit made up by the external inductor, L_R , and internal capacitor, C_R . An optional additional external capacitor can be added for special requirements.

The data will automatically start modulating the rf signal as soon as the chip has powered up to the power-on reset level. The built in voltage protection and regulation insures protection against high voltage from the tank circuit.



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The value of L_R is determined by the following relationship.

$$f_R = 1/(2\pi \sqrt{L_{R^*} C_R})$$

Where f_R is the resonance frequency.

For a typical internal C_R of 170 pf and for f_R at 125 kHz,

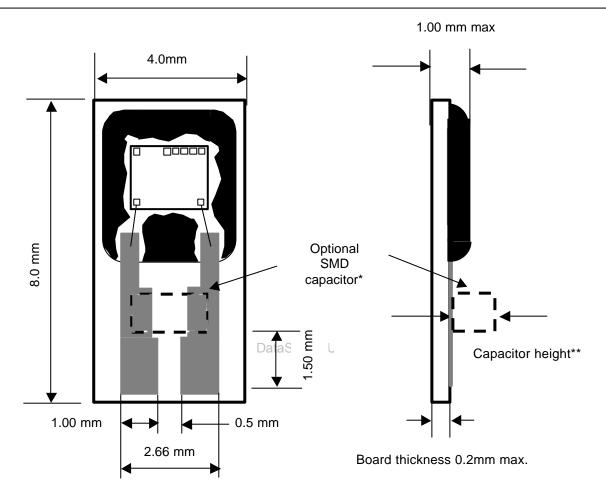
 $L_R = 9.54 \text{ mH}$

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PACKAGE AND ORDERING INFORMATION PCB FORM



*Note that an optional SMD capacitor is not required normally due to internal capacitor on chip. The device is supplied without an SMD capacitor.

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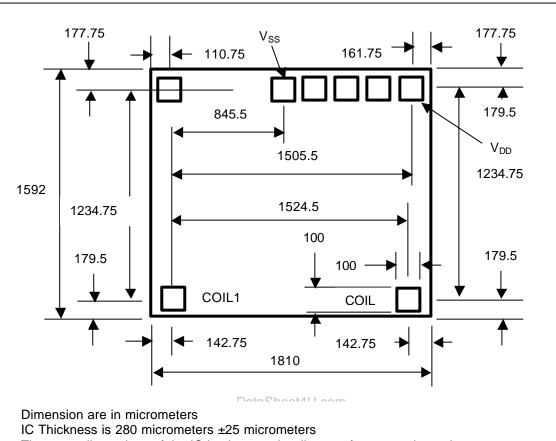
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^{**}Note that the height of some SMD capacitors could exceed the height of the glob.

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CHIP FORM



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The outer dimensions of the IC is given as the distance from saw channel centre to saw channel centre and will be smaller than indicated due to material removed during sawing

ORDERING INFORMATION

Data rate at 32 clocks per bit In Chip form SA7110 32 IC In PCB form SA7110 32 COB

Data rate at 64 clocks per bit In Chip form SA7110 64 IC In PCB form SA7110 64 COB

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